NSN 5961-01-226-2099

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-226-2099 **Inclosure Material:** Metal **Overall Length:** 1.748 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 175.0 collector to base voltage, dc and 175.0 collector to emitter voltage, dc and 15.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 30.00 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig:

A110a0